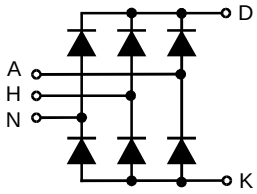
ECO-PAC ™
Three Phase Rectifier Bridge
with Fast Recovery Epitaxial Diodes (FRED)

I_{dAV} = 24 A
V_{RRM} = 1200 V
t_{rr} = 40 ns

V_{RSM} V	V_{RRM} V	Typ
1200	1200	VUE 22-12NO7



Symbol	Conditions		Maximum Ratings	
I_{dAV} ①	T_C = 85°C, module		24	A
I_{dAVM}			90	A
I_{FSM}	T_{VJ} = 45°C	t = 10 ms (50 Hz), sine	40	A
	V_R = 0	t = 8.3 ms (60 Hz), sine	45	A
	$T_{VJ} = T_{VJM}$	t = 10 ms (50 Hz), sine	35	A
	V_R = 0	t = 8.3 ms (60 Hz), sine	40	A
I^2t	T_{VJ} = 45°C	t = 10 ms (50 Hz), sine	10	A^2s
	V_R = 0	t = 8.3 ms (60 Hz), sine	10	A^2s
	$T_{VJ} = T_{VJM}$	t = 10 ms (50 Hz), sine	5	A^2s
	V_R = 0	t = 8.3 ms (60 Hz), sine	5	A^2s
T_{VJ}			-40...+150	°C
T_{VJM}			150	°C
T_{stg}			-40...+125	°C
V_{ISOL}	50/60 Hz, RMS	t = 1 min	3000	V~
	$I_{ISOL} \leq$ 1 mA	t = 1 s	3600	V~
M_d	Mounting torque	(M4)	1.5-2/14-18	Nm/lb.in.
Weight	typ.		19	g

Symbol	Conditions		Characteristic Values typ.	max.	
I_R	$V_R = V_{RRM}$	T_{VJ} = 25°C		0.06	mA
	$V_R = V_{RRM}$	$T_{VJ} = T_{VJM}$		0.25	mA
V_F	I_F = 10 A	T_{VJ} = 25°C		2.92	V
V_{T0}	for power-loss calculations only			1.39	V
r_T				55	mΩ
R_{thJC}	per diode; DC current			2.5	K/W
R_{thCH}	per diode, DC current, typ.			0.3	K/W
I_{RM}	I_F = 12 A, -diF/dt = 100 A/µs		4	8.5	A
	V_R = 100 V, L = 0.05 mH, T_{VJ} = 100°C				
t_{rr}	I_F = 1 A; -di/dt = 50 A/µs; V_R = 30 V, T_{VJ} = 25°C		40	tbd	ns
a	Max. allowable acceleration			50	m/s^2
d_S	creeping distance on surface			11.2	mm
d_A	creepage distance in air			9.7	mm

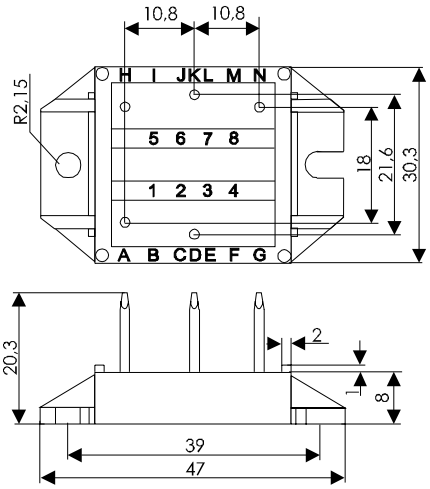
Data according to IEC 60747 refer to a single diode unless otherwise stated
① for resistive load at bridge output.

Features
- Package with DCB ceramic base plate in low profile
- Isolation voltage 3000 V~
- Planar passivated chips
- Low forward voltage drop
- Leads suitable for PC board soldering

Applications
- Supplies for DC power equipment
- Input and output rectifiers for high frequency
- Battery DC power supplies
- Field supply for DC motors

Advantages
- Space and weight savings
- Improved temperature and power cycling capability
- Small and light weight
- Low noise switching

Dimensions in mm (1 mm = 0.0394")



IXYS reserves the right to change limits, test conditions and dimensions.

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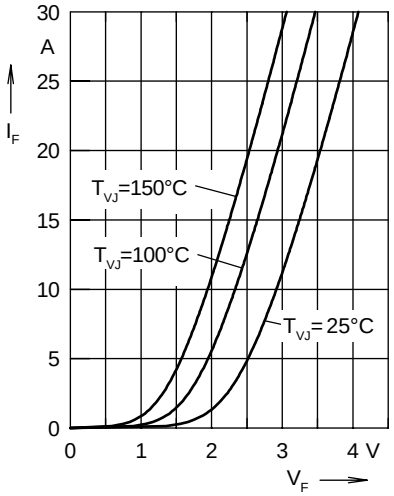

Fig. 1 Forward current I_F versus V_F

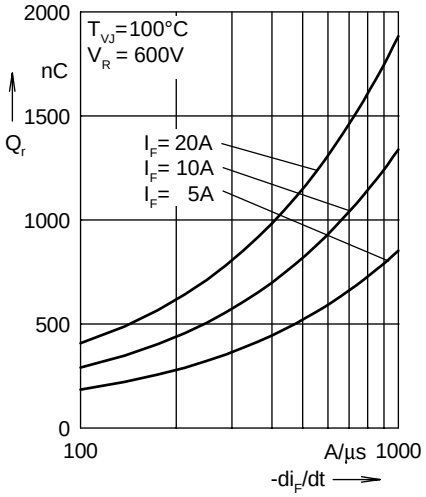

Fig. 2 Reverse recovery charge Q_r versus $-di_F/dt$

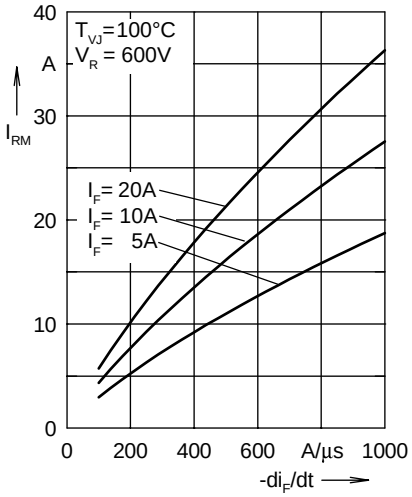

Fig. 3 Peak reverse current I_{RM} versus $-di_F/dt$

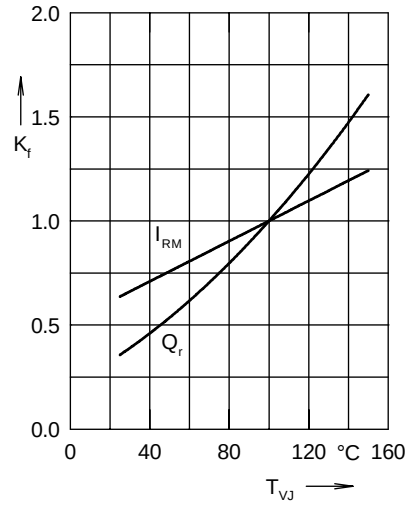

Fig. 4 Dynamic parameters Q_r, I_{RM} versus T_{VJ}

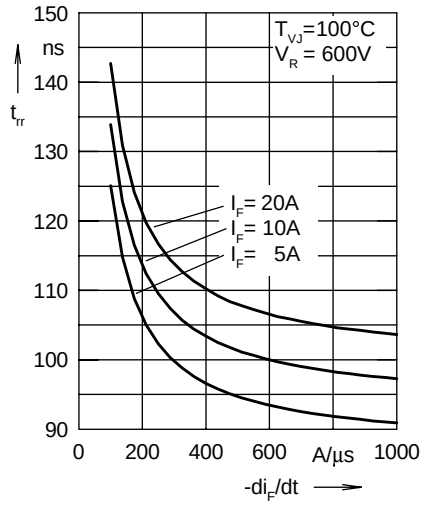

Fig. 5 Recovery time t_{rr} versus $-di_F/dt$

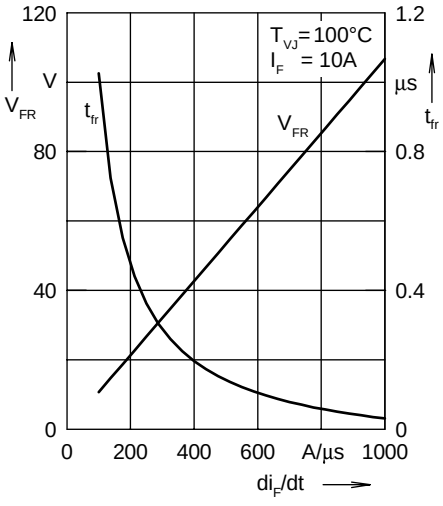

Fig. 6 Peak forward voltage V_{FR} and t_{fr} versus di_F/dt

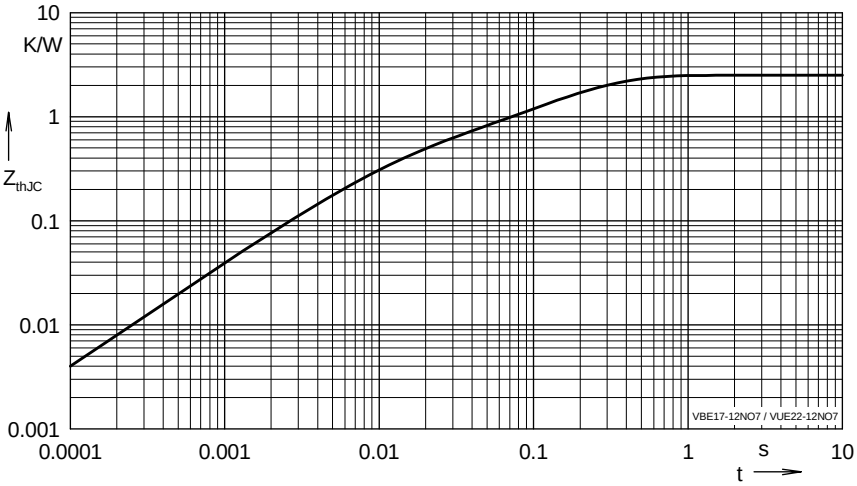

Fig. 7 Transient thermal resistance junction to case

Constants for Z_{thJC} calculation:

i	R_{thi} (K/W)	t_i (s)
1	0.8776	0.0052
2	0.3378	0.0003
3	0.0678	0.0004
4	1.2168	0.0092

NOTE: Fig. 2 to Fig. 6 shows typical values